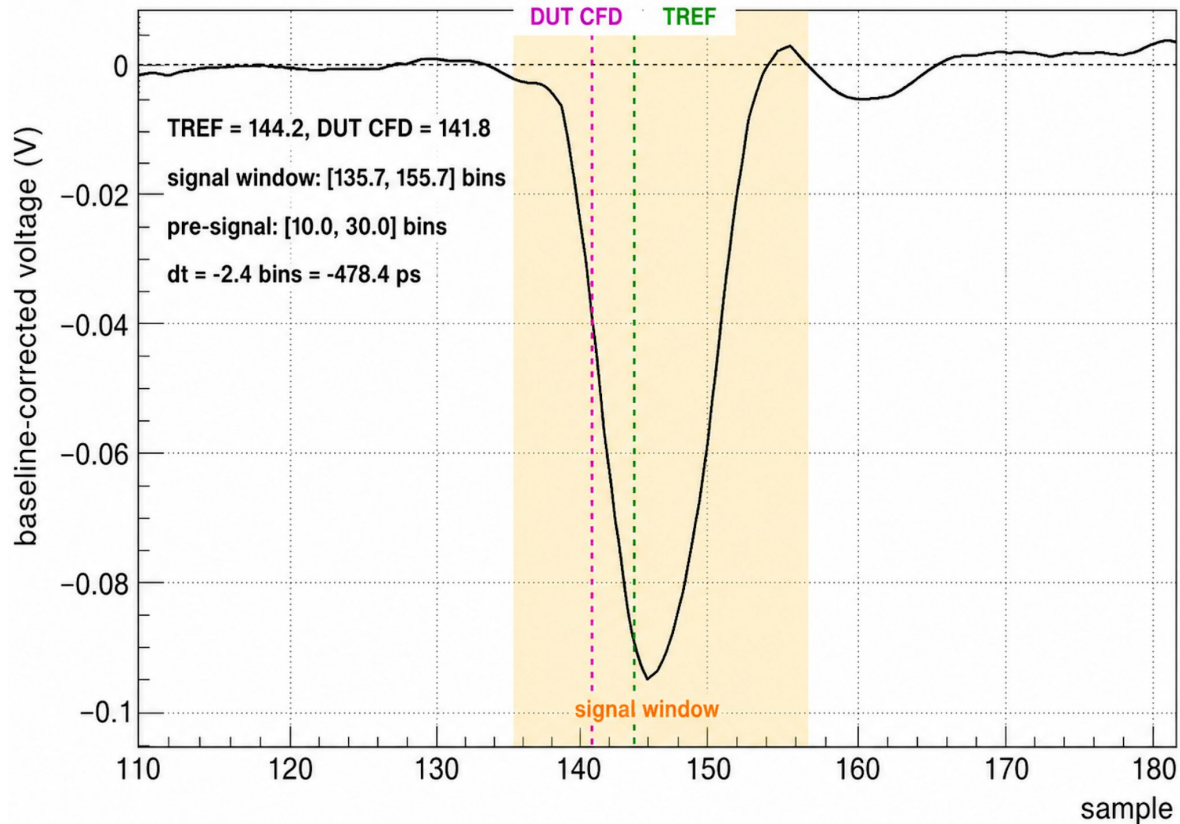
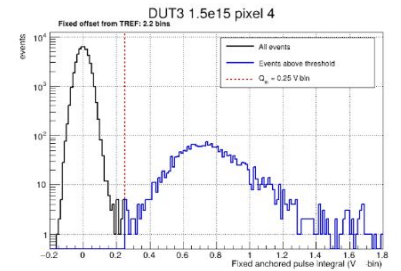
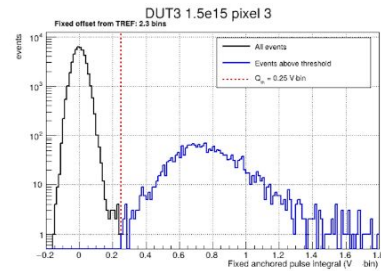
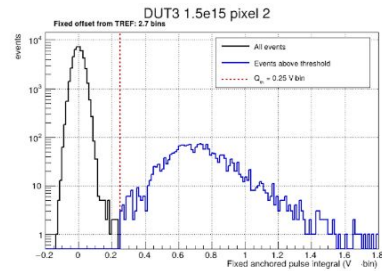
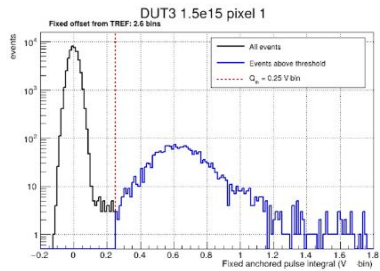
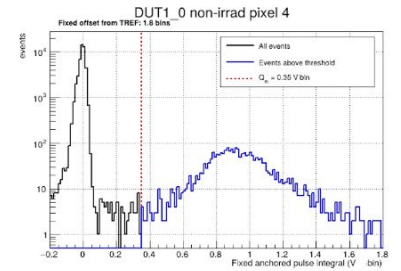
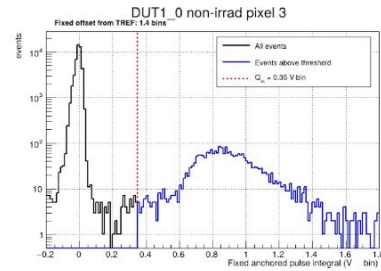
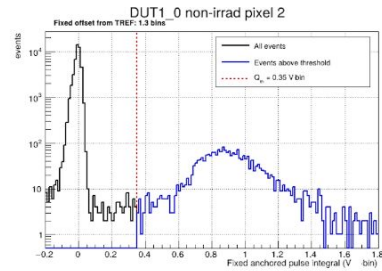
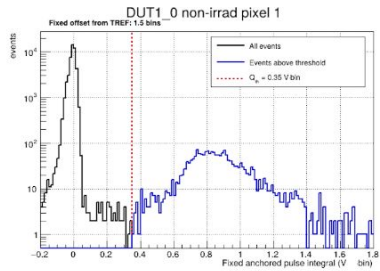


Fixed-anchor signal extraction and timing definition

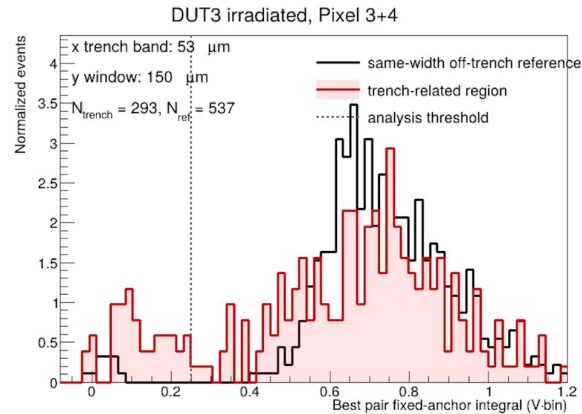
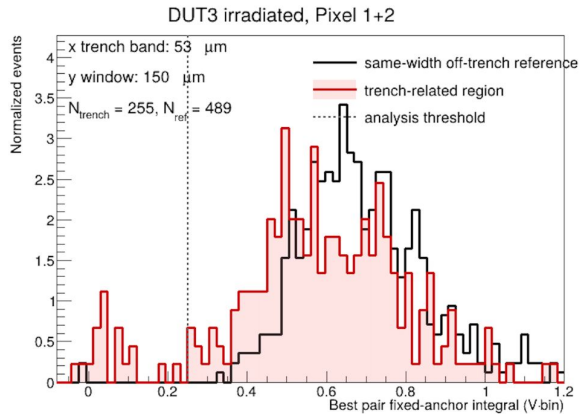
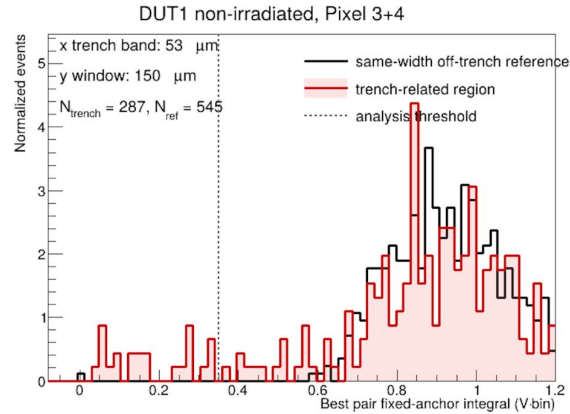
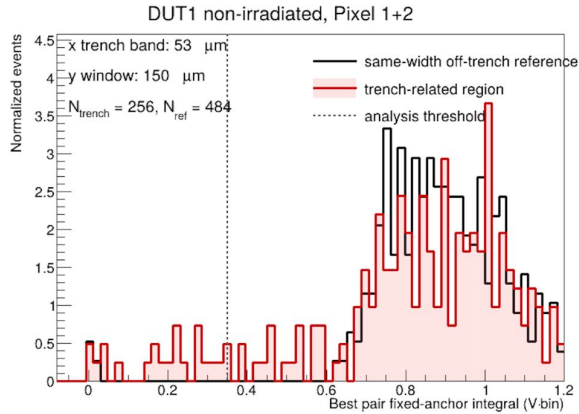


- TREF CFD defines the event time anchor
- Same-length pre-signal window used for baseline reference
- $dt = t_{\text{DUT}} - t_{\text{REF}}$
- The DUT charge is integrated in a fixed 20-bin window placed relative to the TREF CFD anchor, to avoid the pedestal bias of peak-centering while retaining the main part of the DUT pulse for the selected events in this run

TI LGAD structure: V2-TR1-TW2/TW3



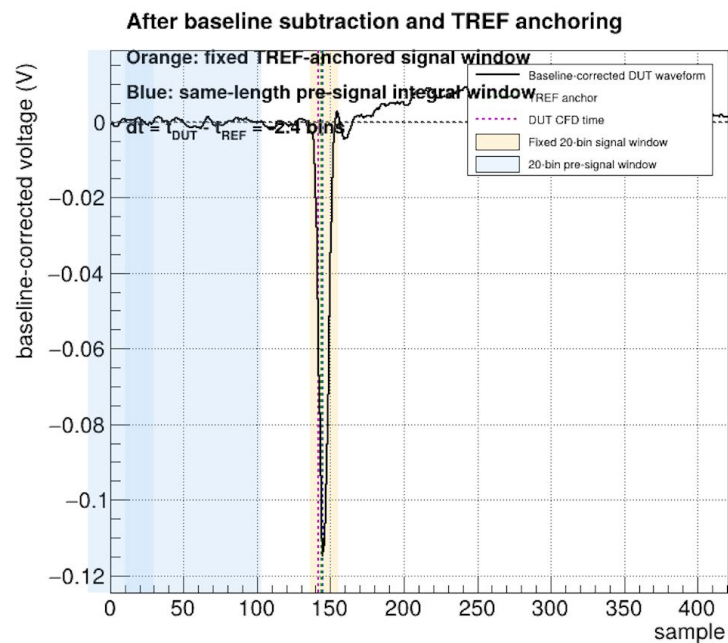
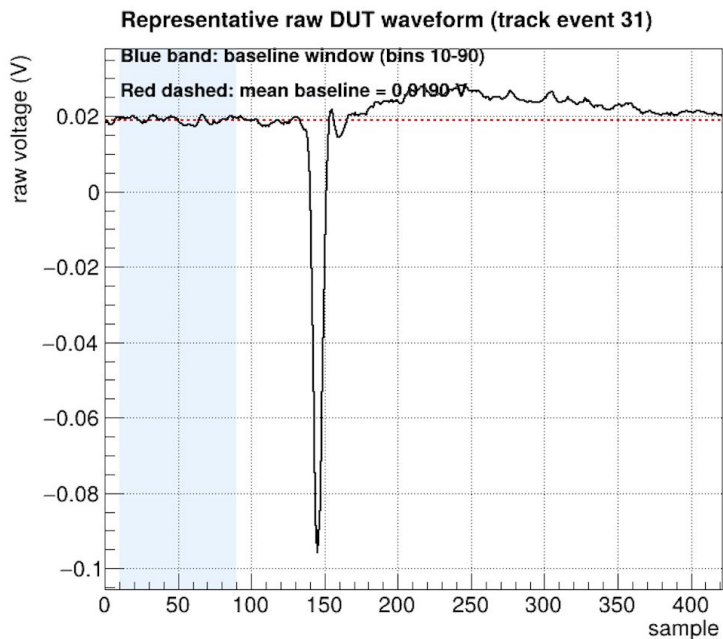
How does the trench-region signal spectrum compare to a nearby non-trench region?



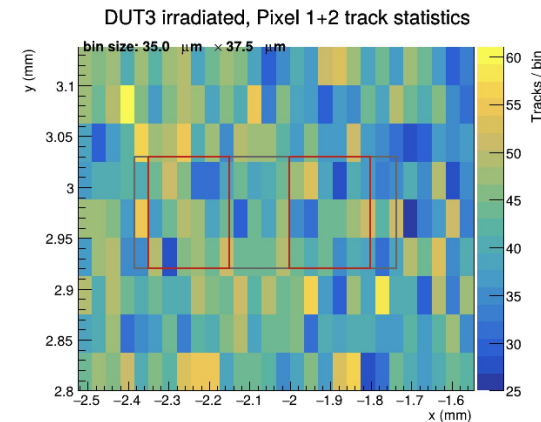
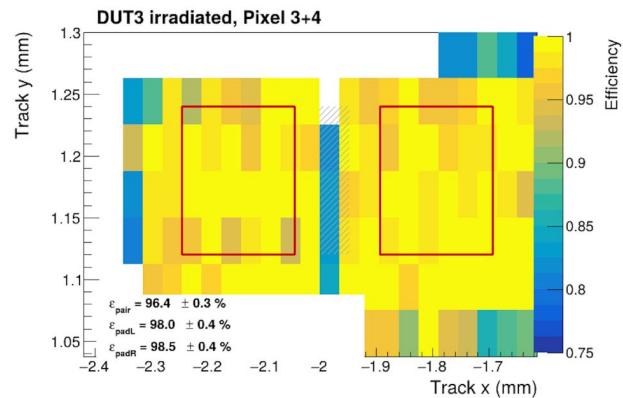
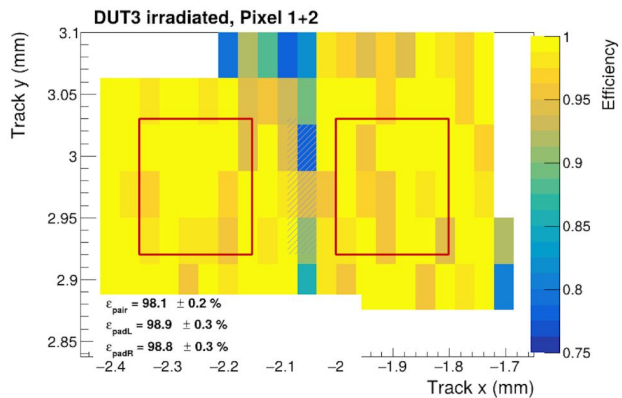
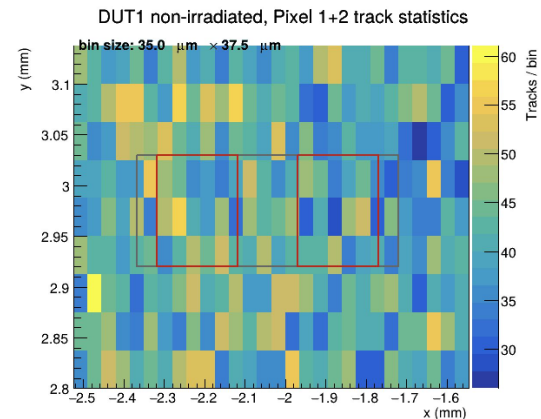
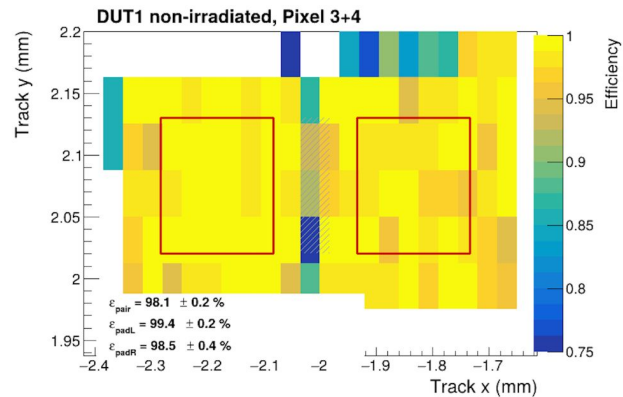
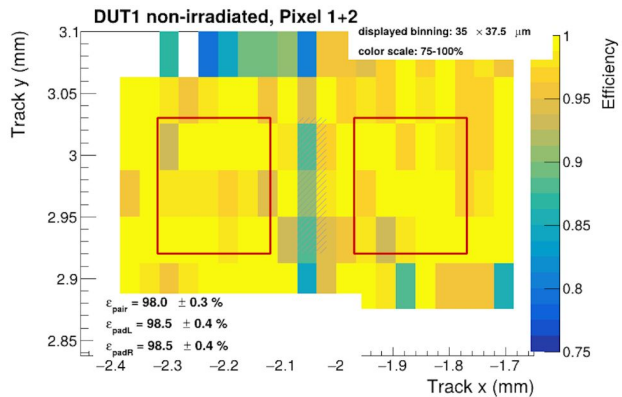
The trench-related region shows a lower-charge population than the off-trench reference region, which is consistent with the local efficiency loss.

Example event showing the fixed TREF-anchored signal definition

- REF waveform defines the time anchor.
- DUT signal is integrated in a fixed 20-bin window relative to that anchor.
- A same-length pre-signal window is used for the baseline reference.
- dt is the time difference between DUT and reference.



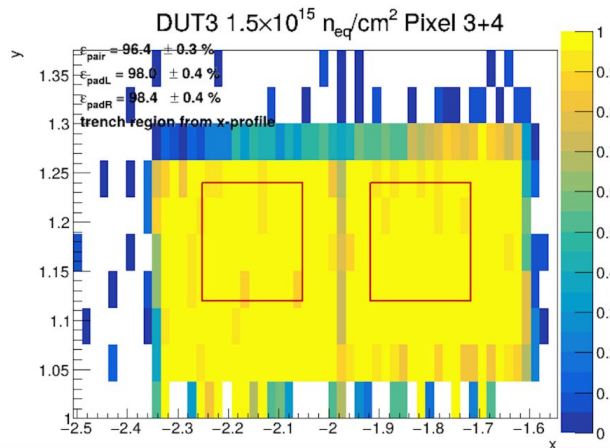
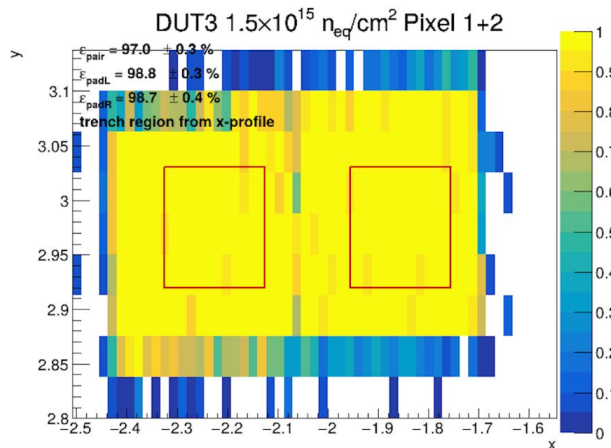
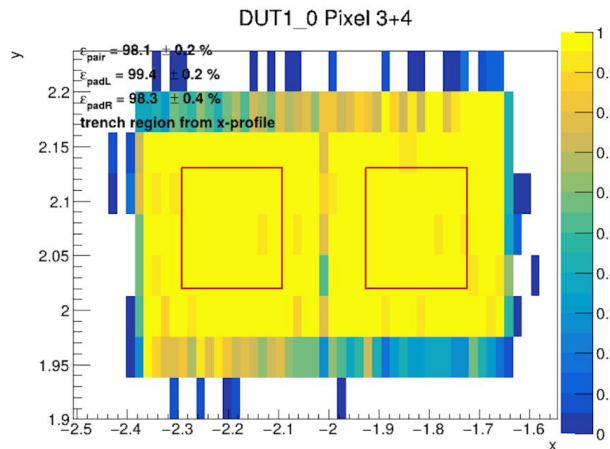
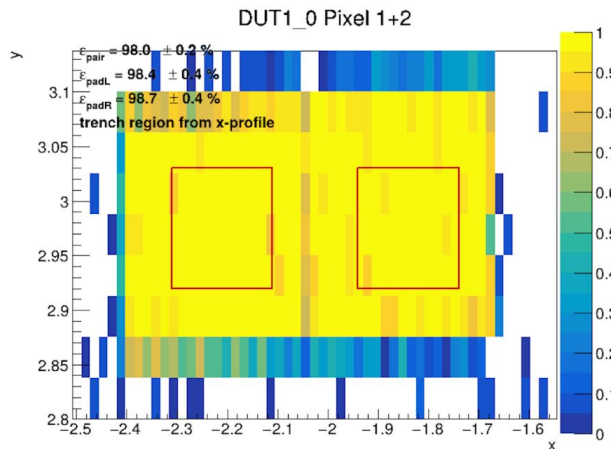
Binning: $35 \times 37.5 \mu\text{m}$



Typical local statistics: about 40–43 tracks/bin

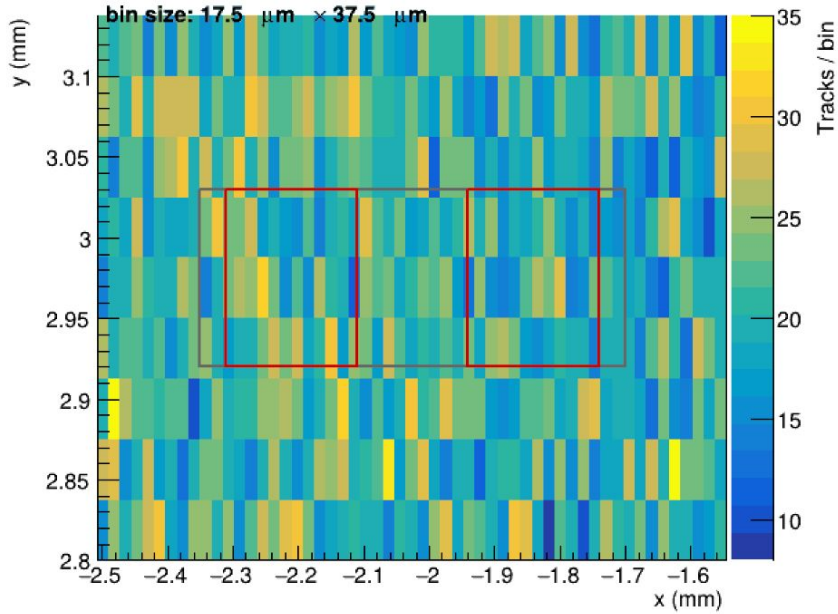
Efficiencies

Binning: $17.5 \mu\text{m} \times 37.5 \mu\text{m}$

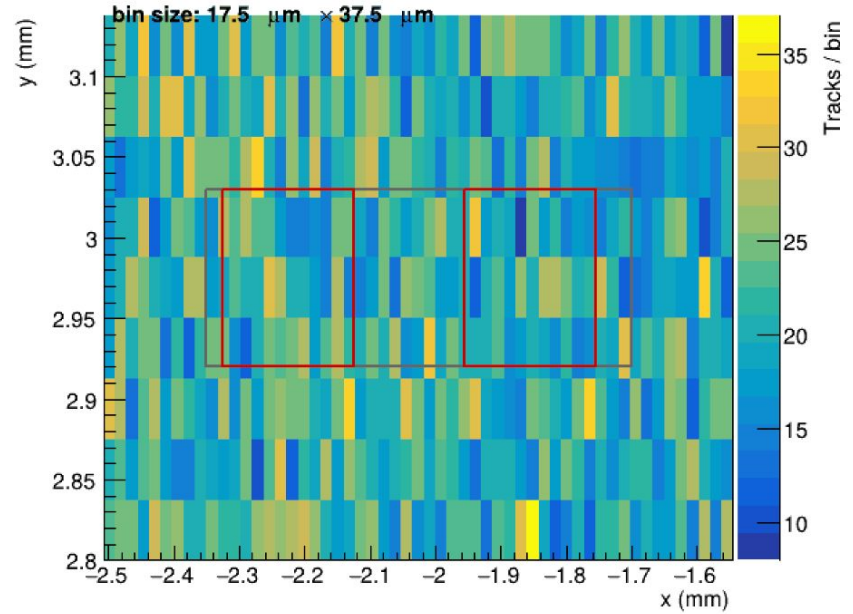


- Pad-only ROIs exclude the trench
- Left and right pad efficiencies quoted separately
- Pair inefficiency is partly driven by the trench region

DUT1_0 Pixel 1+2 track statistics



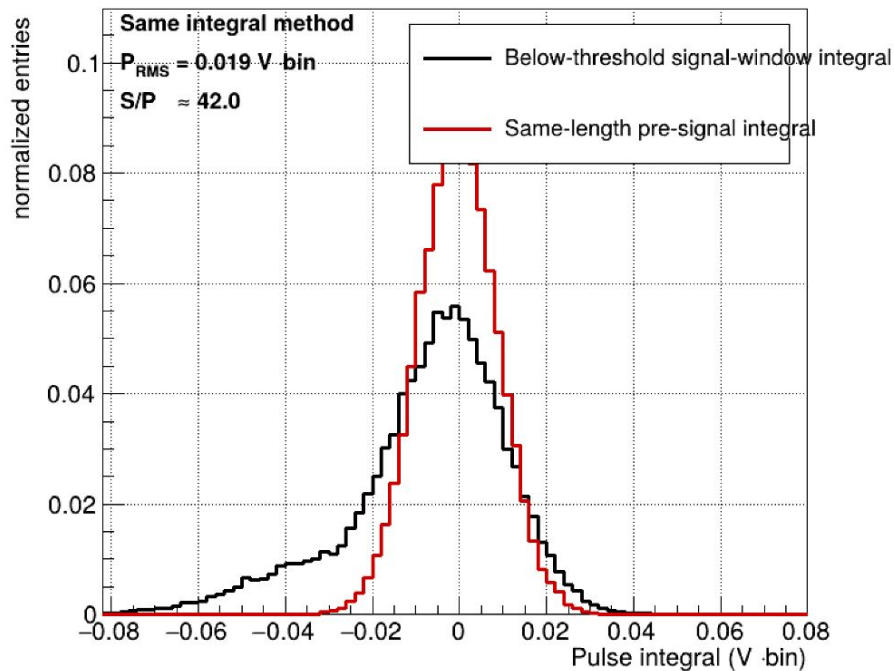
DUT3 $1.5 \times 10^{15} n_{\text{eq}}/\text{cm}^2$ Pixel 1+2 track statistics



- Track-statistics map shown to indicate local entries per bin-> Typical local statistics: about 17 tracks/bin

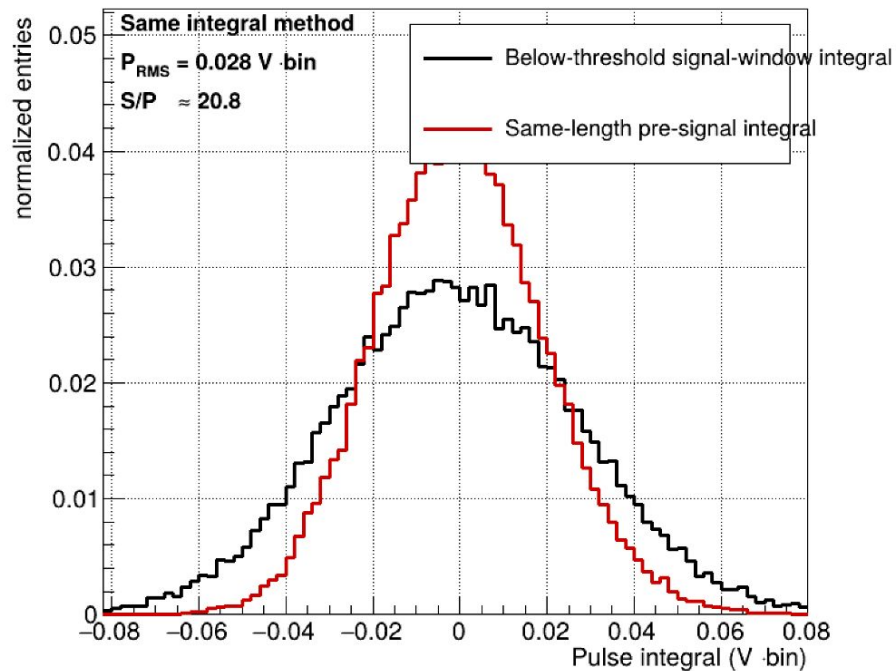
DUT1_0 non-irrad pixel 1

Pedestal-focused comparison

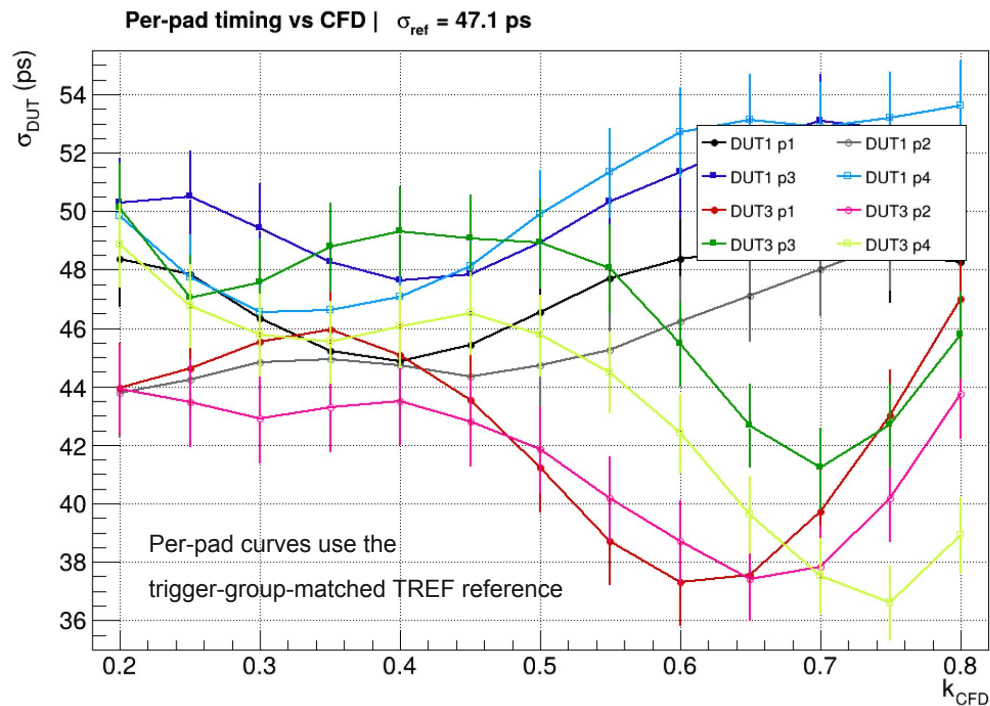


DUT3 1.5e15 pixel 1

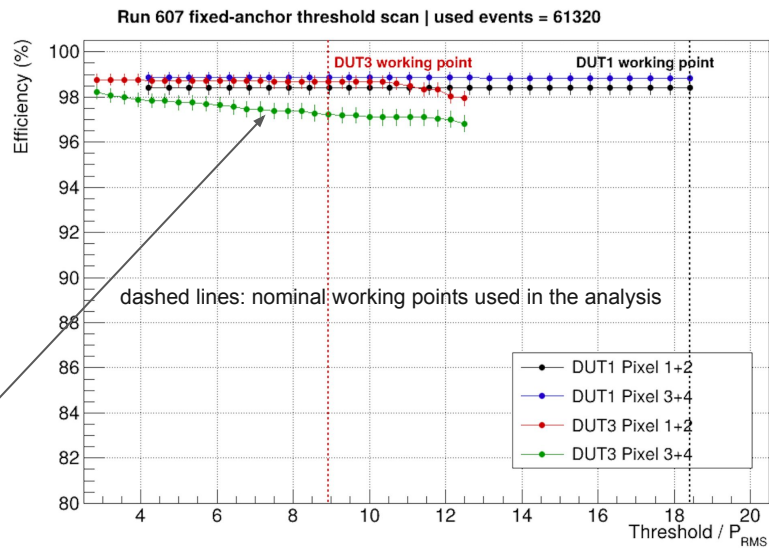
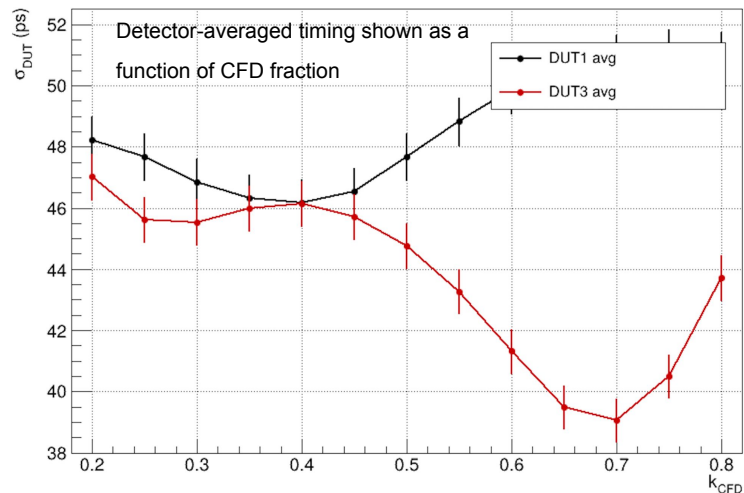
Pedestal-focused comparison



Threshold and CFD scans with track-based fixed-anchor selection

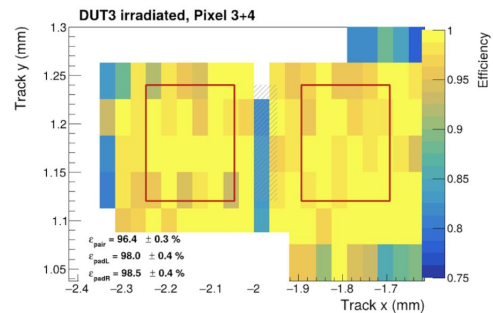
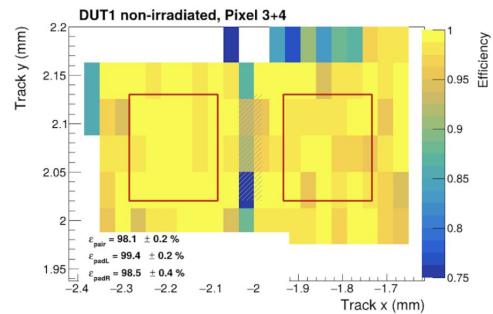
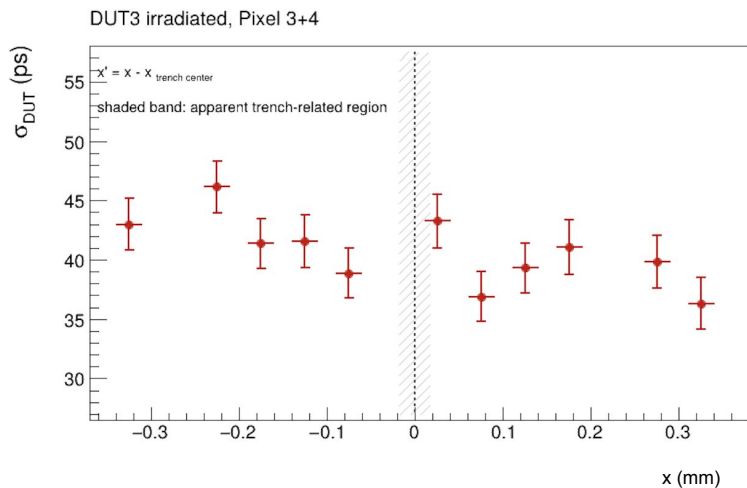
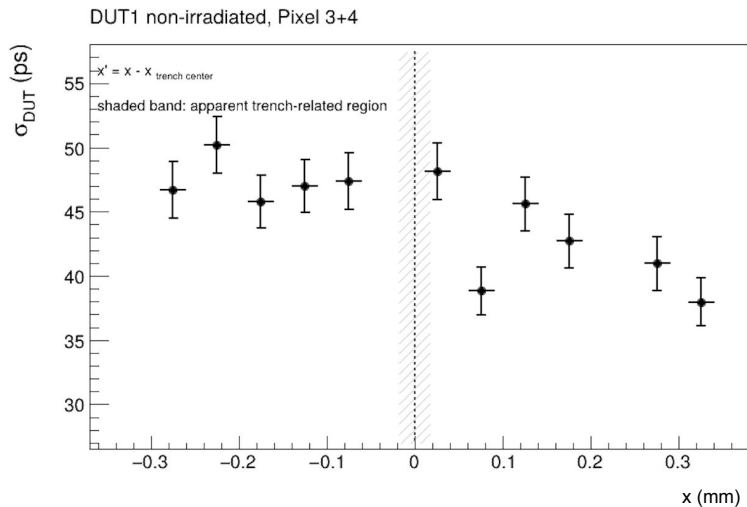


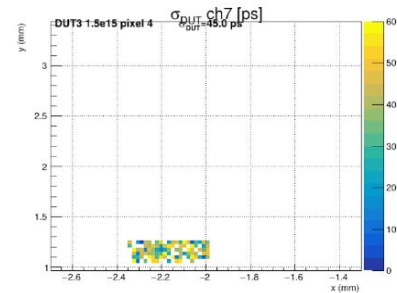
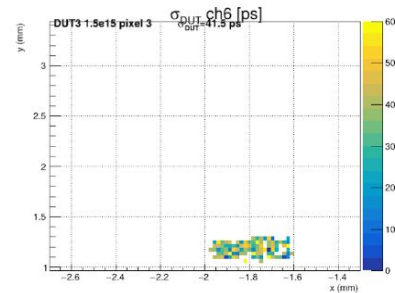
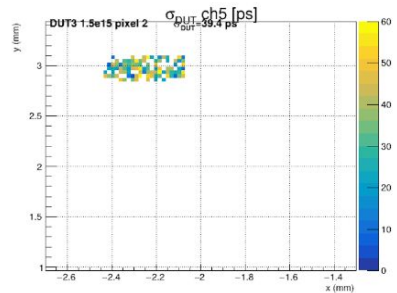
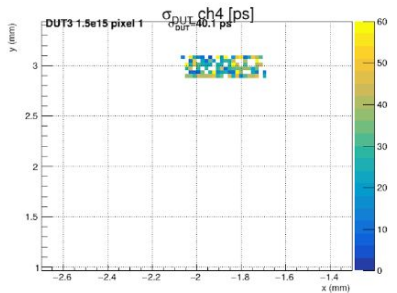
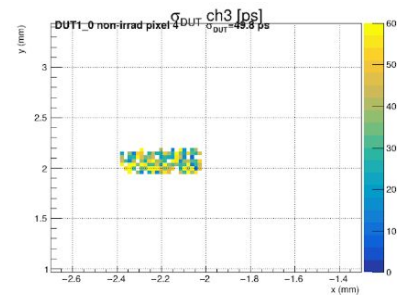
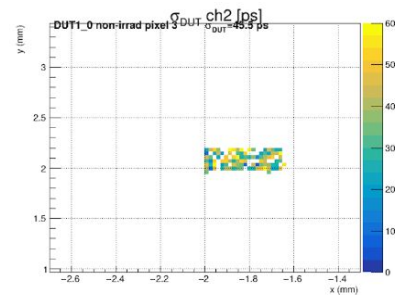
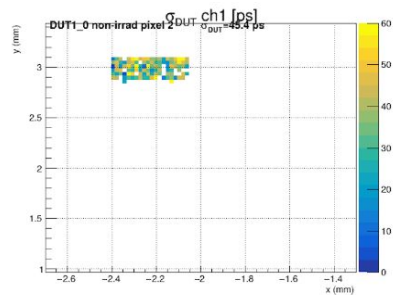
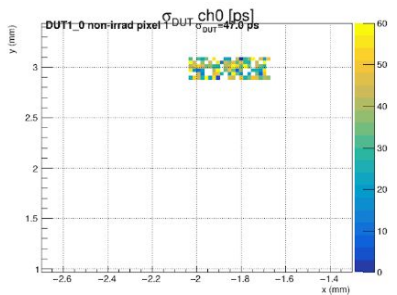
Threshold choice is much more critical for DUT3 than for DUT1



Trench-centered timing x-projection plots

- Timing projected in x after aligning each pair to its own trench center
- Grey band: apparent trench-related region from the efficiency x-profile
- No strong universal timing degradation is observed

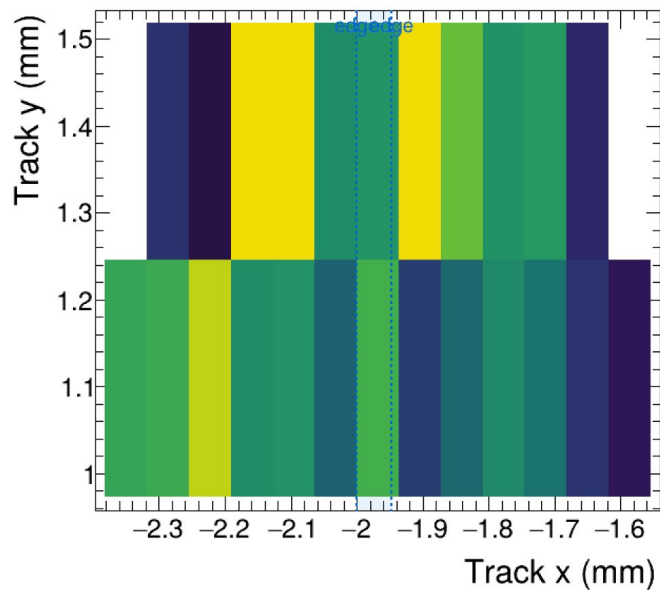




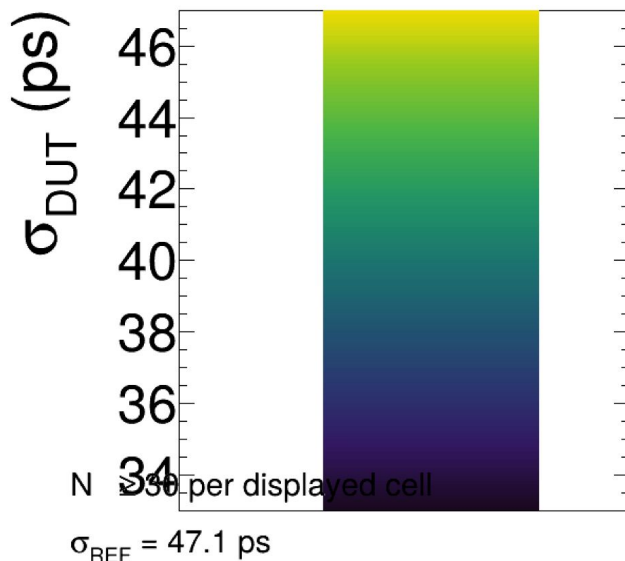
- Direct local Δ ToA RMS map on the efficiency grid
- Same-grid timing map tested in a separate rerun
- Per-cell timing statistics are too sparse for a stable final 2D presentation
- Used as a validation cross-check, not as the main timing result

2D local timing map

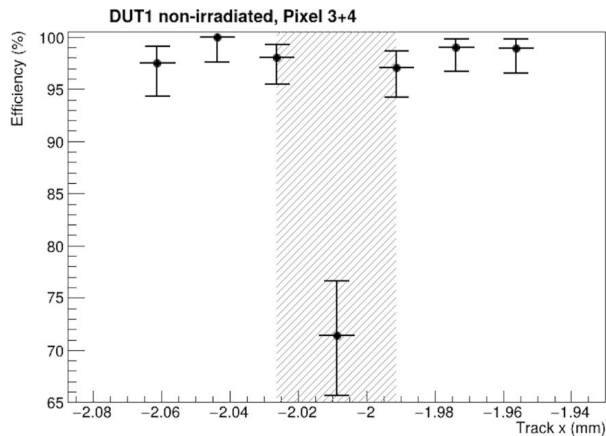
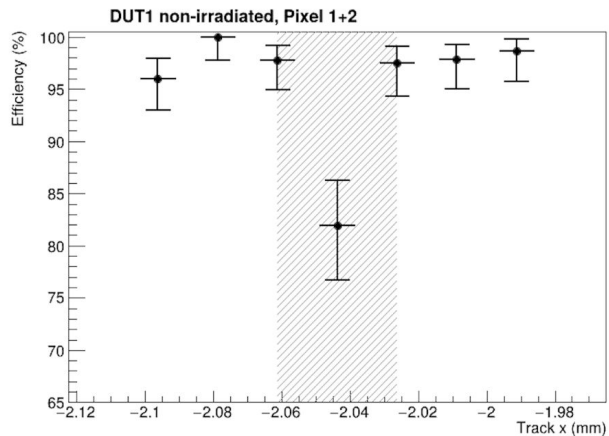
DUT3 irradiated, Pixel 3+4



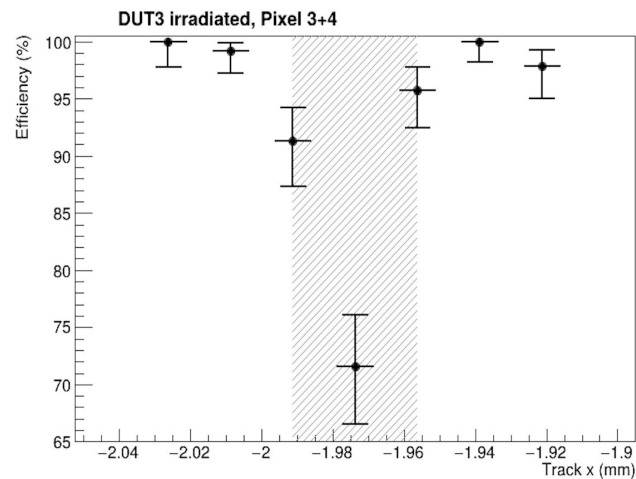
Direct local Δ ToA RMS



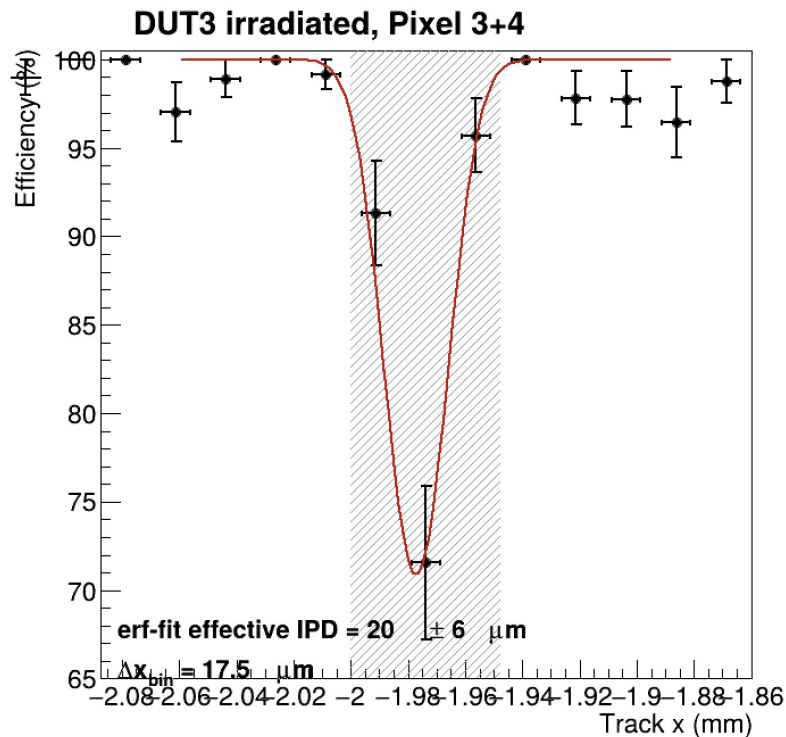
- Direct local Δ ToA RMS map
- DUT3 irradiated, Pixel 3+4
- Blue dashed lines: trench edges from efficiency x-profile
- Only cells with $N \geq 30$ timing entries shown



- Efficiency projected in x for the full pair ROI
- Error bars: Clopper–Pearson 68.3% confidence intervals
- Grey band: apparent trench-related region from the efficiency x-profile
- DUT3 shows a clear localized efficiency dip in the apparent trench-related region



Effective IPD estimate from the efficiency dip



- Summed x projection for DUT3 irradiated, with an error-function fit to the trench-related efficiency dip

$$\varepsilon(x) = p - (A/2) * [\text{erf}((x - xL)/\sigma) - \text{erf}((x - xR)/\sigma)]$$

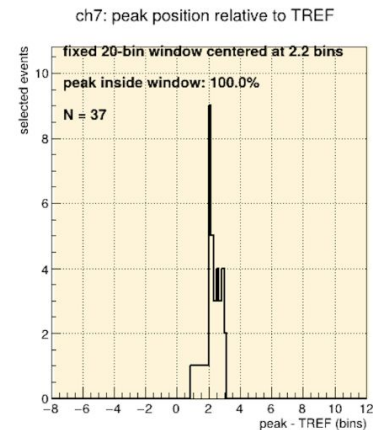
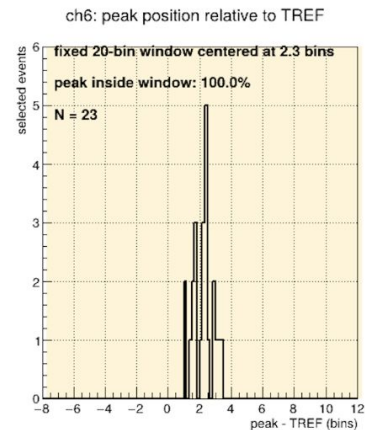
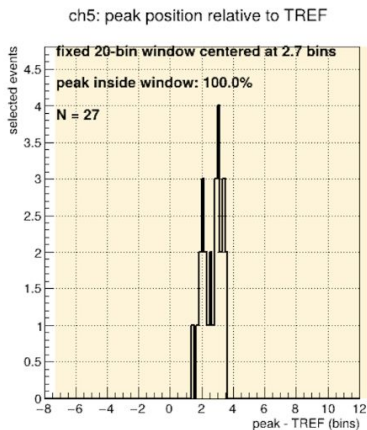
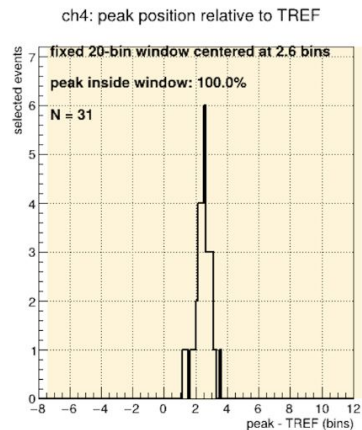
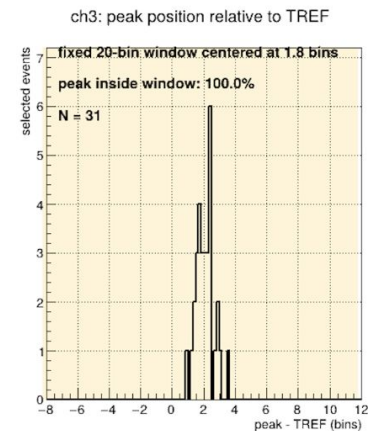
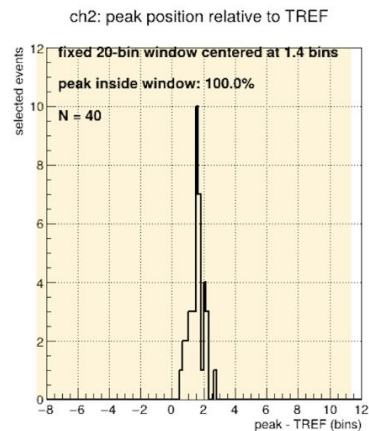
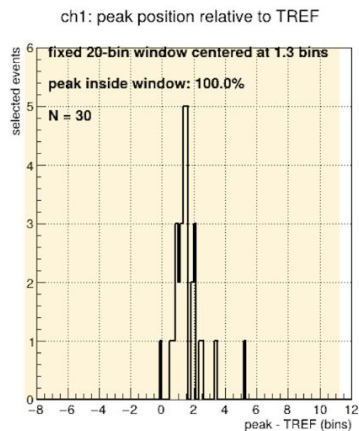
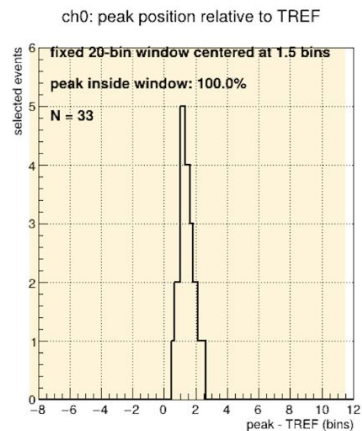
with parameters:

- p : plateau efficiency
- A : dip amplitude
- xL, xR : effective dip edges
- σ : edge-smearing scale

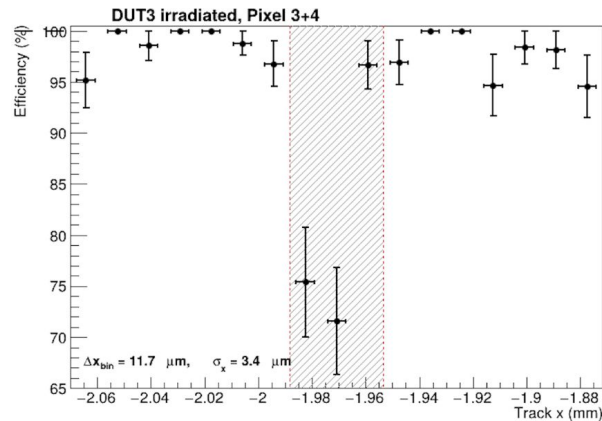
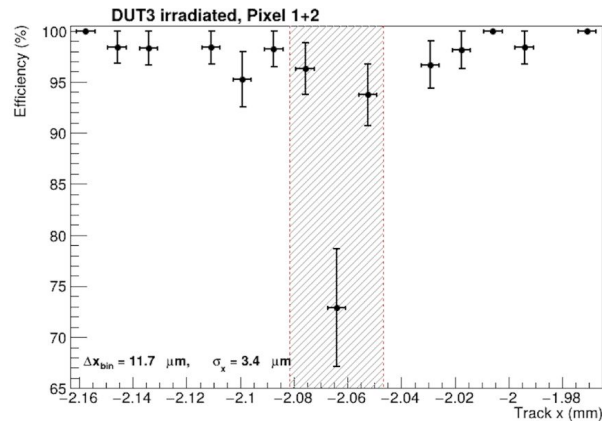
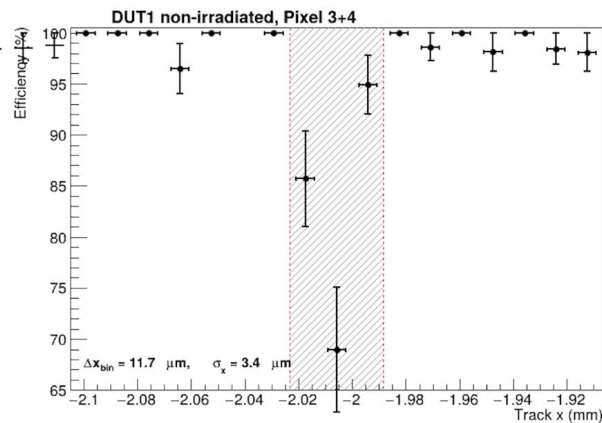
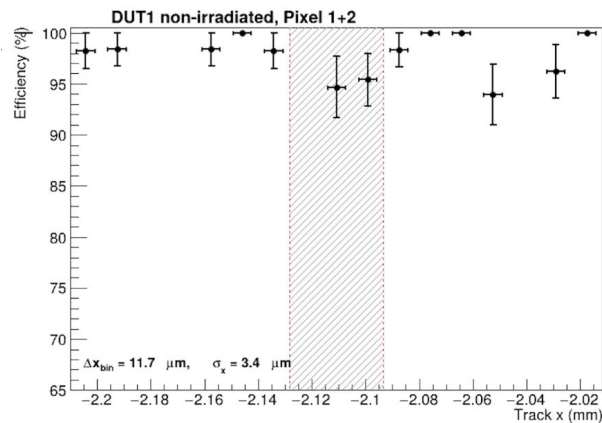
- Larger dip-region errors reflect lower local track statistics
- Grey band: data-driven apparent trench-related region from the efficiency x-profile
- Effective IPD: model-dependent response width of the dip, not physical trench width

Validation for the signal definition: peakPos - tTREF

- Validation of the fixed TREF-anchored signal window
- Observed DUT pulse remains inside the chosen window

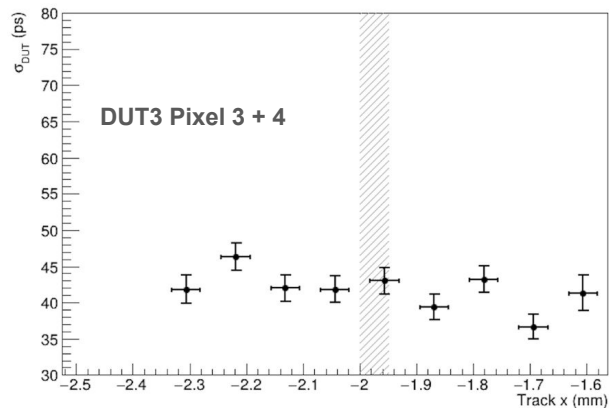
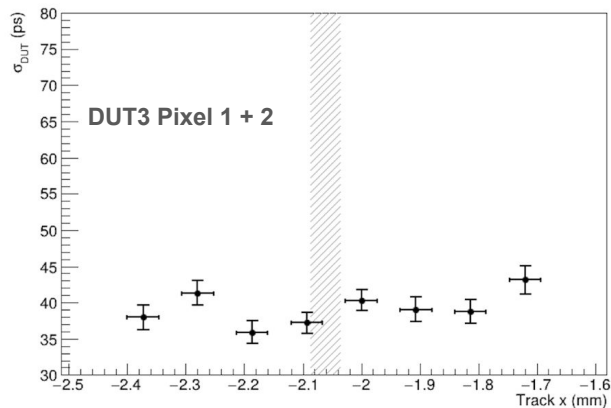
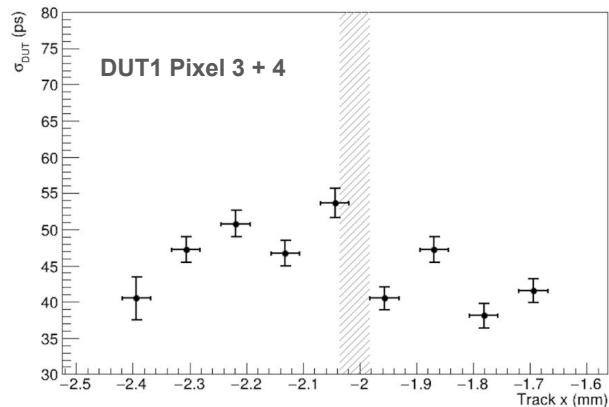
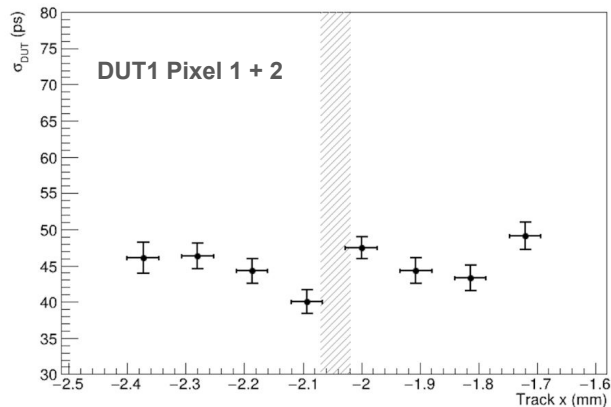


Efficiency x projection: localized trench-related band



- Center-y efficiency projected in x
- Shaded band: trench-related inefficient region
- Used to localize the trench-related response dip

Timing projected in x near the trench



- Timing evaluated as a function of track x
- Shaded band: apparent trench-related region from the efficiency x-profile
- No strong timing degradation is observed

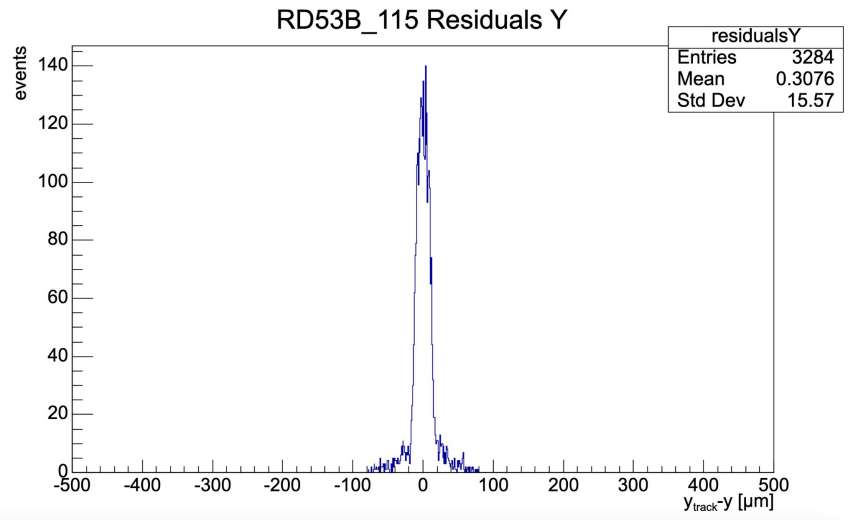
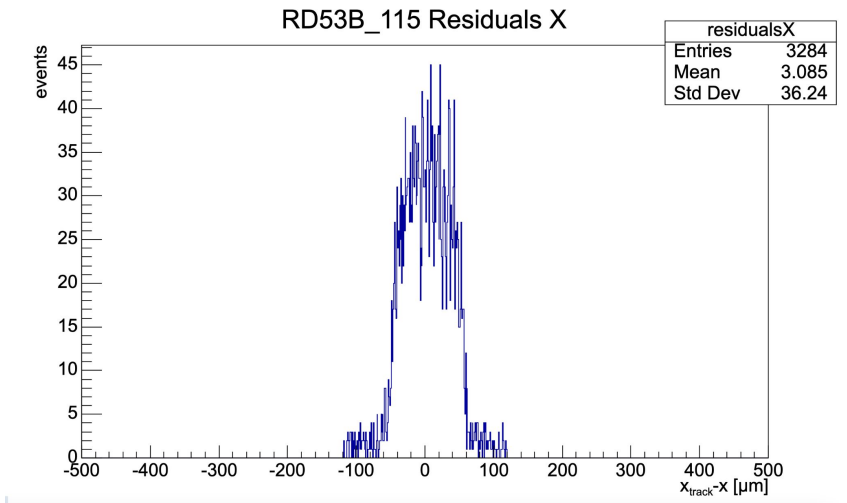
Interesting testbeam runs to analyse >>

Important: calibration for Chubut2 board with PIN TI-LGAD to be done

Ongoing analysis: Batch 1 -> March TB 2026; 100 um x 25 um CROC

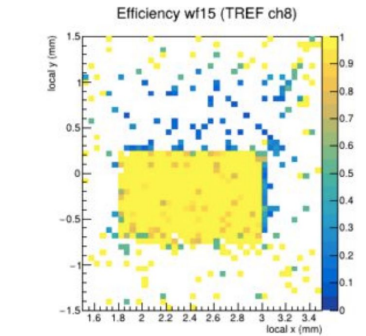
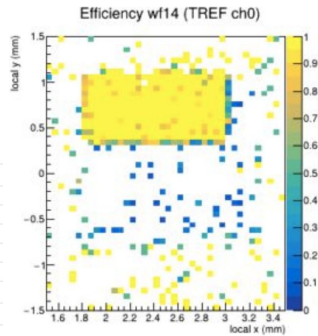
Batch 1						
Wafer	Version	Trench parameter	Fluence	# daughterboard	Chubut CH1,2	Chubut CH3,4
W5	V2	TW1-2			V2TW1	V2TW2
W5	V2	TW1-2			V2TW1	V2TW2
W5	V1-V2	TW5			V1TW5	V2TW5
W5	V1-V2	TW5			V1TW5	V2TW5

HV plane 1 (V) TREF1 - Genova	HV plane 2 (V) DUT1 - UZH	HV plane 3 (V) DUT2 - UZH	HV plane 4 (V) DUT3 - UZH	HV plane 5 (V) DUT4 - UZH
220V; 0.07uA	240V; 11.3uA	240V; 12.9uA	200V; 13.2uA	200V 20.0uA

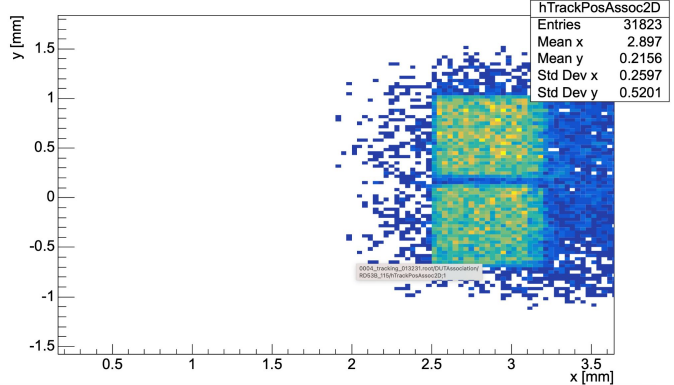


Batch 1 -> March TB 2026; 100 um x 25 um CROC, efficiency plots with the CROC included;
select only tracks that passed through the CROC active region; run 13231 -> checked another batch -> improvement of
associated tracks for the CROC ; batch 3 has masked columns in CROC

Batch 2+3								
Wafer	Version	Trench parameter	Fluence	# daughterboard	Chubut CH1,2	Chubut CH3,4		
W5	V2	TW1-2		0	V2TW1	V2TW2	Angled	
W5	V2	TW2-3	2.5e15		V2TW2	V2TW3		
W2	V2	TW2-3	2.5e15		V2TW2	V2TW3	CH3+4 not used for Batch 3	
W5	V2	TW4-6	1.5E15		V2TW4	V2TW6	CH3+4 not used for Batch 2	
Batch 4								
Wafer	Version	Trench parameter	Fluence	# daughterboard	Chubut CH1,2	Chubut CH3,4		
MB13	W2	V1-V2	TW5	1.5e15	V1TW5	V2TW5	Angled	
MB7	W2	V1-V2	TW5	2.5e15	V1TW5	V2TW5	DUT5 from March26	
MB14	W2	V2	TW1-2	2.50E+15	V2TW1	V2TW2	DUT14 from March26	
MB15	W5	V2	TW4-6	2.5e15	V2TW4	V2TW6	(DUT13 from Oct25)	
Update:	W2	V1-V2	TW5	1.5e15	V1TW5	V2TW5	DUT10 from March Sample broken	
	W5	V2	TW4/6	2.5e15	V2TW4	V2TW6	DUT6 from Oct 25	
	W5	V2	TW4/6	2.5e15	V2TW4	V2TW6	DUT 9 from March	

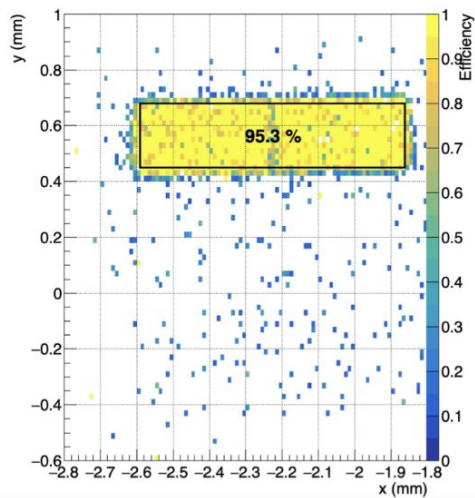


Track position in global coordinates of those which had been associated to a cluster

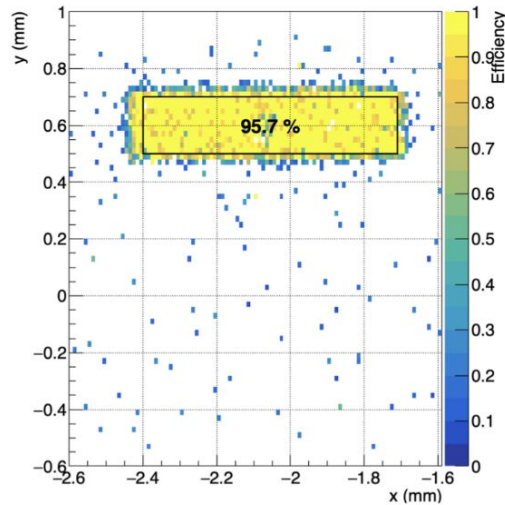


Batch 6							
Wafer	Version	Trench parameter	Fluence	# daughterboard	Chubut CH1,2	Chubut CH3,4	
55um	W11	V1-2	TW5		V1TW5	V1TW5	Angled
	W11	V2	TW2-3		V2TW2	V2TW3	
	W11	V2	TW4-6		V2TW4	V2TW6	FRIPS - broken
	W11	V3-4	TW5		V3TW5	V4TW5	
Replacement:	W3	V1-2	TW5		V1TW5	V2TW5	Zurich Sample

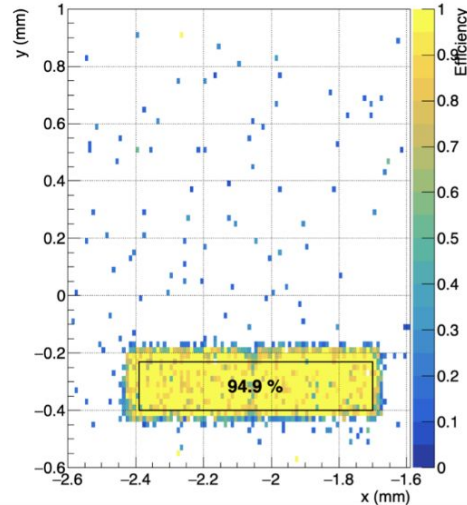
Next step: Testbeam October 2024 -> regenerate plots with the new TB analysis



(a) Unirradiated TW5, 50 V.
 $S/N_{\text{peak}} = 48$, $S/N_{\text{cut}} = 13$



(b) Irradiated TW4, 530 V.
 $S/N_{\text{peak}} = 68$, $S/N_{\text{cut}} = 25$



(c) Irradiated TW6, 530 V.
 $S/N_{\text{peak}} = 68$, $S/N_{\text{cut}} = 25$